

NMUX1308A-Q100

1.5 V to 5.5 V, 8-channel analog switch multiplexer and demultiplexer with injection-current control

Rev. 1 — 16 May 2025

Product data sheet

1. General description

The NMUX1308A-Q100 is a general purpose, CMOS, bi-directional, 8 channel analog switch, with an operating voltage range of 1.5 V to 5.5 V. The NMUX1308A-Q100 is dual source compatible with existing 4851 and 4051 devices. The NMUX1308A-Q100 extends the digital logic thresholds to be compatible with 1.8 V systems without the need for voltage translation.

The analog signal pins are bi-directional and are comprised of a single common input/output (Z) and eight independent inputs/outputs (Y0 to Y7).

All analog signal pins support overvoltage and undervoltage protection through the integration of injection current control circuitry. This circuit clamps analog signals biased above VCC or biased below GND, saving the need for external overvoltage and undervoltage clamp components (e.g. resistor diode network). This circuit also preserves measurement accuracy of the connected analog signal path by isolating overvoltage events from shifting the device operating voltage.

There are four control signal pins (S0, S1, S2, and \overline{E}). S0, S1, and S2 determine the analog channels to connect between Z and Yn. \overline{E} can be used to override S0, S1, and S2, disconnecting all analog channels.

The control signal pins support 1.8 V logic thresholds across all operating voltages. In addition, these pins are 5.5 V tolerant, enabling up to 5.5 V operation independent of supply voltage.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- SP8T-Z functionality
- Wide operating range: 1.5 V to 5.5 V
- · Rail-to-Rail operation on analog signal pins
- Injection current control: 0.1 mV measurement voltage offset up to 10 mA of injected current
- 1.8 V digital logic thresholds
 - Digital pins compatible with 1.8 V logic thresholds across full V_{CC} range
 - Removes need for up-translation device for compatibility with low voltage GPIOs
- I_{off} circuitry
 - Enables wider latitude for power sequencing considerations
 - Isolates backflow between supply rail and any biased digital/analog input when V_{CC} = 0 V
 - Prevents any biased digital/analog input from backpowering V_{CC} when V_{CC} = 0 V
- 5.5 V overvoltage tolerant digital inputs
 - Supports switching of 5.5 V digital signals across full V_{CC} operating range
 - Removes need for down-translation when switching thresholds are met
- Pin compatible with industry standard 4051 and 4851 analog switch products
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C2b exceeds 750 V
- DHVQFN package with Side-Wettable Flanks enabling Automated Optical Inspection (AOI) of solder joints

3. Applications

- Body control module
- Battery management system
- · Automotive head unit



4. Ordering information

Table 1. Ordering information

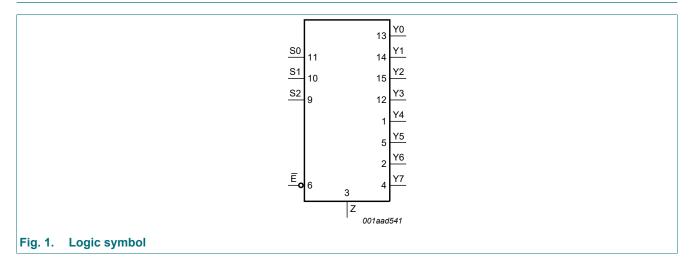
Type number	Package								
	Temperature range	Name	Description	Version					
NMUX1308APW-Q100	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1					
NMUX1308ABQ-Q100	-40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 × 3.5 × 0.85 mm	SOT763-1					

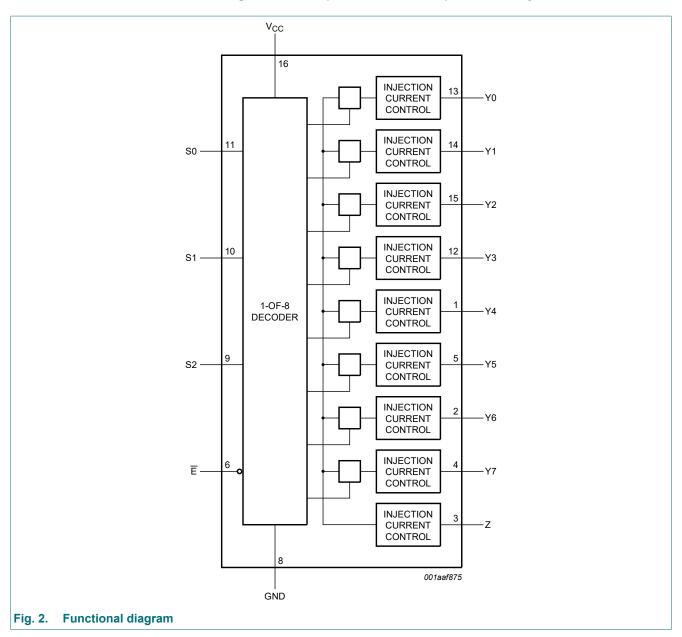
5. Marking

Table 2. Marking

Type number	Marking code
NMUX1308APW-Q100	NM1308A
NMUX1308ABQ-Q100	M1308A

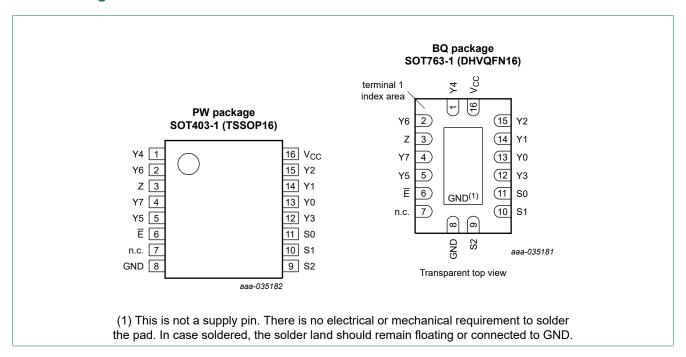
6. Functional diagram





7. Pinning information

7.1. Pinning



7.2. Pin description

Table 3. Pin description

Symbol	Pin	Description
Y4	1	independent input/output
Y6	2	independent input/output
Z	3	common input/output
Y7	4	independent input/output
Y5	5	independent input/output
Ē	6	enable input (active LOW); do not leave this pin floating
n.c.	7	not connected
GND	8	ground (0 V)
S2	9	select input; do not leave this pin floating
S1	10	select input; do not leave this pin floating
S0	11	select input; do not leave this pin floating
Y3	12	independent input/output
Y0	13	independent input/output
Y1	14	independent input/output
Y2	15	independent input/output
V _{CC}	16	supply voltage

8. Functional description

8.1. Overview

The NMUX1308A-Q100 is a general purpose analog switch with a single pole that can be configured to select between one of eight possible connection paths (SP8T). Each analog connection path is bi-directional, with similar electrical characteristics independent of the direction of signal propagation.

8.2. Key features

Injection current control

Current injection can occur in systems where an analog voltage can experience transient spikes due to signal propagation over long distances with high inductance. Voltage exposure above the supply voltage will source excessive current into an analog input, which is referred to as positive injection. Voltage exposure below the ground voltage will sink excessive current from an analog input, which is referred to as negative injection. Both types of injection current elevate the risk of device damage to an analog input and can introduce a large voltage error to the analog signal itself.

The NMUX1308A-Q100 mitigates both risks by integrating an injection current control circuit, which acts as a voltage clamp to divert both positive injection and negative injection through a bypass FET that connects to GND. This implementation minimizes any shift in the supply voltage, therefore minimizing any shift in the device's ON Resistance, and thus minimizes changes in the measured analog voltage. The injection current control circuit is active on all analog pins, independent of whether the channel is selected/unselected.

1.8 V Compatible digital logic thresholds

It is common for modern systems to operate digital signals from lower voltage nodes such as 1.8 V, while operating their analog signals at higher voltage nodes such as 3.3 V or 5.0 V. To remove the requirements for a voltage translation device, the NMUX1308A-Q100 digital control pins maintain 1.8 V logic compatible thresholds at higher operating voltages, up to 5.5 V

loff protection circuitry of digital inputs

The NMUX1308A-Q100 implements I_{off} protection circuitry on the digital control pins, isolating those pins from the internal circuits when the supply is unpowered (i.e., V_{CC} = 0 V). The ESD protection diodes on the digital input pins do not have a connection path to V_{CC} . If the digital input pins are biased when the V_{CC} pin is unpowered:

- 1. The high impedance of the digital input pins minimizes input current leakage.
- 2. The isolation between the digital input pins and the V_{CC} pin ensures no back-powering to the supply rail.



Note: There will be a current draw into the respective analog switch pin, and system design must ensure that the current draw is within the NMUX1308A-Q100 recommended operating conditions.

loff protection circuitry of analog inputs/outputs

The NMUX1308A-Q100 implements I_{off} protection circuitry on the analog switch pins, isolating those pins from the internal circuits when the supply is unpowered (i.e., V_{CC} = 0 V). The ESD protection diodes on the analog switch pins do not have a connection path to V_{CC} . If the analog switch pins are biased when the V_{CC} pin is unpowered:

- 1. The isolation between the analog pins and the V_{CC} pin ensures no back-powering to the supply rail.
- 2. The high impedance of the analog switch path itself minimizes signal coupling across the switch.

Table 4. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level; \ X = don't \ care.$

Input				Channel ON
E	S2	S1	S0	
L	L	L	L	Y0 to Z
L	L	L	Н	Y1 to Z
L	L	Н	L	Y2 to Z
L	L	Н	Н	Y3 to Z
L	Н	L	L	Y4 to Z
L	Н	L	Н	Y5 to Z
L	Н	Н	L	Y6 to Z
L	Н	Н	Н	Y7 to Z
Н	Х	Х	Х	-

9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+6.0	V
VI	input voltage	E, S0, S1, S2 [1]	-0.5	+6.0	V
V_{SW}	switch voltage	Yn, Z [2]	-0.5	V _{CC} + 0.5	V
I _{SW}	switch current	Yn, Z; $V_{SW} > -0.5 \text{ V or } V_{SW} < V_{CC} + 0.5 \text{ V};$ $T_{amb} = -40 ^{\circ}\text{C} \text{ to } +85 ^{\circ}\text{C}$	-50	+50	mA
		Yn, Z; $V_{SW} > -0.5 \text{ V or } V_{SW} < V_{CC} + 0.5 \text{ V};$ $T_{amb} = -40 \text{ °C to } +125 \text{ °C}$	-25	+25	mA
I _I	input current	E, S0, S1, S2	-30	30	mA
I_{GND}	ground current		-100	100	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$ [3]	-	500	mW
Tj	junction temperature		-	+150	°C

^[1] The minimum and maximum input voltage rating may be exceeded if the input clamping current rating is observed.

^[2] The minimum and maximum switch voltage rating may be exceeded if the switch clamping current rating is observed.

^[3] For SOT403-1 (TSSOP16) package: P_{tot} derates linearly with 8.5 mW/K above 91 °C.
For SOT763-1 (DHVQFN16) package: P_{tot} derates linearly with 11.2 mW/K above 106 °C.

10. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CC}	supply voltage		1.5	-	5.5	V
VI	input voltage	Ē, S0, S1, S2	0	-	5.5	V
V_{SW}	switch voltage	Yn, Z; enable and disable mode	0	-	V _{CC}	V
I _{SW}	switch current	Yn, Z; V_{SW} > GND or V_{SW} < V_{CC} ; T_{amb} = -40 °C to +85 °C	-50	-	50	mA
		Yn, Z; V_{SW} > GND or V_{SW} < V_{CC} ; T_{amb} = -40 °C to +125 °C	-25	-	25	mA
I _{SK}	switch clamping current	$Yn, Z; V_{SW} < GND \text{ or } V_{SW} > V_{CC}$ [1]	-50	-	50	mA
I _{GND}	ground current		-100	-	100	mA
I _{INJ}	injected current	single off switch	-25	-	50	mA
		all off switches combined	-100	-	100	mA
T _{amb}	ambient temperature		-40	-	+125	°C

^[1] If the V_{SW} > V_{CC} or if V_{SW} < GND, the pin will be shunted to GND through an internal FET. The current must be limited within the specified value.

11. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground 0 V); for test circuit see Fig. 5.

Symbol	Parameter	Conditions		25 °C		-40 °C to	+85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
Analog switch				•						•
R _{ON}	ON resistance	$V_I = V_{CC}$ to GND; $I_{SW} = 0.5$ mA; $\overline{E} = V_{IL}$; see Fig. 5								
		V _{CC} = 1.8 V ± 10%	-	450	1151	-	1245	-	1245	Ω
		V _{CC} = 2.5 V ± 10%	-	160	388	-	419	-	436	Ω
		V _{CC} = 3.3 V ± 10%	-	95	231	-	262	-	278	Ω
		V _{CC} = 5 V ± 10%	-	60	146	-	167	-	178	Ω
ΔR _{ON}	ON resistance mismatch	$V_I = 0.5V_{CC}$; $I_{SW} = 0.5 \text{ mA}$; $E = V_{IL}$								
	between channels	V _{CC} = 1.8 V ± 10%	-	5	91	-	91	-	91	Ω
	Charineis	V _{CC} = 2.5 V ± 10%	-	4	35	-	39	-	41	Ω
		V _{CC} = 3.3 V ± 10%	-	2	17	-	19	-	19	Ω
		V _{CC} = 5 V ± 10%	-	1	11	-	11	-	12	Ω

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	1
I _{S(OFF)}	OFF-state leakage current	Yn pins; switch off; \overline{E} = V _{IH} ; V _I = 0.8V _{CC} or 0.2V _{CC} ; V _O = 0.2V _{CC} or 0.8V _{CC} ; see Fig. 3								
		V _{CC} = 1.8 V ± 10%	-	±1	-	-25	25	-800	800	nA
		V _{CC} = 2.5 V ± 10%	-	±1	-	-25	25	-800	800	nA
		V _{CC} = 3.3 V ± 10%	-	±1	-	-25	25	-800	800	nA
		V _{CC} = 5 V ± 10%	-	±1	-	-25	25	-800	800	nA
		Z pins; switch off; $\overline{E} = V_{IH}$; $V_I = 0.8V_{CC}$ or $0.2V_{CC}$; $V_O = 0.2V_{CC}$ or $0.8V_{CC}$; see Fig. 3								
		V _{CC} = 1.8 V ± 10%	-	±1	-	-45	45	-800	800	nA
		V _{CC} = 2.5 V ± 10%	-	±1	-	-45	45	-800	800	nA
		V _{CC} = 3.3 V ± 10%	-	±1	-	-45	45	-800	800	nA
		V _{CC} = 5 V ± 10%	-	±1	-	-45	45	-800	800	nA
I _{S(ON)}	ON-state leakage current	Z, Yn pins; switch on; $\overline{E} = V_{IL}$; $V_I = V_O = 0.8V_{CC}$ or $V_I = V_O = 0.2V_{CC}$; see Fig. 4								
		V _{CC} = 1.8 V ± 10%	-	±1	-	-45	45	-800	800	nA
		V _{CC} = 2.5 V ± 10%	-	±1	-	-45	45	-800	800	nA
		V _{CC} = 3.3 V ± 10%	-	±1	-	-45	45	-800	800	nA
		V _{CC} = 5 V ± 10%	-	±1	-	-45	45	-800	800	nA
C _{SW}	switch capacitance	Yn pins, OFF-state; V _I = 0.5V _{CC} ; f = 1 MHz								
		V _{CC} = 1.8 V ± 10%	-	3	10	-	10	-	10	pF
		V _{CC} = 2.5 V ± 10%	-	3	9	-	9	-	9	pF
		V _{CC} = 3.3 V ± 10%	-	3	9	-	9	-	9	pF
		V _{CC} = 5 V ± 10%	-	3	9	-	9	-	9	pF
		Z pin, OFF-state; V _I = 0.5V _{CC} ; f = 1 MHz								
		V _{CC} = 1.8 V ± 10%	-	14	23	-	23	-	23	pF
		V _{CC} = 2.5 V ± 10%	-	14	22	-	22	-	22	pF
		V _{CC} = 3.3 V ± 10%	-	14	21	-	22	-	22	pF
		V _{CC} = 5 V ± 10%	-	13	20	-	20	-	20	pF
		Z, Yn pins, ON-state; V _I = 0.5V _{CC} ; f = 1 MHz								
		V _{CC} = 1.8 V ± 10%	-	27	31	-	32	-	32	pF
		V _{CC} = 2.5 V ± 10%	-	27	31	-	31	-	31	pF
		V _{CC} = 3.3 V ± 10%	-	27	30	-	31	-	31	pF
		V _{CC} = 5 V ± 10%	-	26	29	-	30	-	30	рF

Symbol	Parameter	Conditions	25 °C -		-40 °C to +85 °C		-40 °C to	Unit		
			Min	Тур	Max	Min	Max	Min	Max	
Power supply										
I _{CC} supply cu	supply current	E, Sn inputs; V _I = GND or V _{CC}								
		V _{CC} = 1.8 V ± 10%	-	-	1	-	1	-	1	μΑ
		V _{CC} = 2.5 V ± 10%	-	-	1	-	1	-	1	μΑ
		V _{CC} = 3.3 V ± 10%	-	-	1	-	1	-	1	μΑ
		V _{CC} = 5 V ± 10%	-	-	1	-	1	-	1	μA

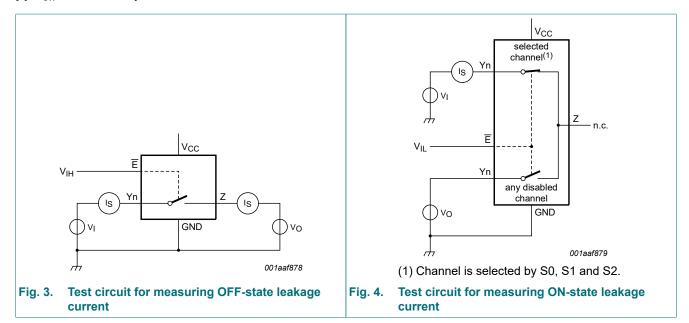
Table 8. Static characteristics

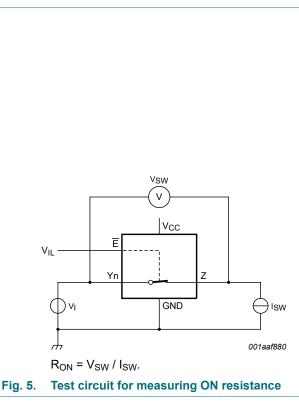
At recommended operating conditions; voltages are referenced to GND (ground 0 V); for test circuit see Fig. 6.

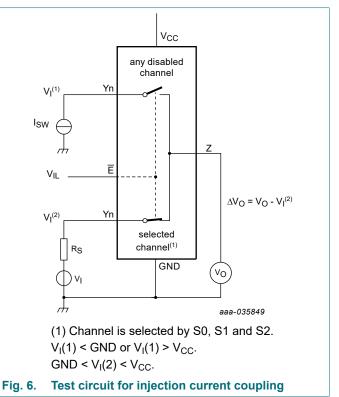
Symbol	Parameter	Conditions		-4	40 to +125 °	С	Unit
				Min	Typ [1]	Max	
Injection	current coupling						
ΔV _O	output voltage variation	$I_{SW} \le 1 \text{ mA}; R_S \le 3.9 \text{ k}\Omega$	[2][3]				
		V _{CC} = 1.8 V ± 10%		-	0.1	1	mV
		V _{CC} = 3.3 V ± 10%		-	0.2	1	mV
		V _{CC} = 5 V ± 10%		-	0.4	2	mV
		$I_{SW} \le 10 \text{ mA}; R_S \le 3.9 \text{ k}\Omega$	[2][3]				
		V _{CC} = 1.8 V ± 10%		-	0.1	2	mV
		V _{CC} = 3.3 V ± 10%		-	0.2	2	mV
		V _{CC} = 5 V ± 10%		-	0.4	2	mV
		$I_{SW} \le 1 \text{ mA}; R_S \le 20 \text{ k}\Omega$	[2][3]				
		V _{CC} = 1.8 V ± 10%		-	0.1	2	mV
		V _{CC} = 3.3 V ± 10%		-	0.2	2	mV
		V _{CC} = 5 V ± 10%		-	0.4	2	mV
		$I_{SW} \le 10 \text{ mA}; R_S \le 20 \text{ k}\Omega$	[2][3]				
		V _{CC} = 1.8 V ± 10%		-	0.1	5	mV
		V _{CC} = 3.3 V ± 10%		-	0.2	5	mV
		V _{CC} = 5 V ± 10%		-	0.4	5	mV
Logic inp	outs						
V _{IH}	HIGH-level input voltage	V _{CC} = 1.8 V ± 10%		0.99	-	5.5	V
		V _{CC} = 2.5 V ± 10%		1.08	-	5.5	V
		V _{CC} = 3.3 V ± 10%		1.15	-	5.5	V
		V _{CC} = 5 V ± 10%		1.32	-	5.5	V
V _{IL}	LOW-level input voltage	V _{CC} = 1.8 V ± 10%		0	-	0.53	V
		V _{CC} = 2.5 V ± 10%		0	-	0.61	V
		V _{CC} = 3.3 V ± 10%		0	-	0.68	V
		V _{CC} = 5 V ± 10%		0	-	0.79	V
I _{IH}	HIGH-level input current	V _I = 1.8 V or V _{CC}		-	-	1	μΑ
I _{IL}	LOW-level input current	V _I = 0 V		-1	-	-	μA

Symbol	Parameter	Conditions	-40 to +125 °C			Unit
			Min	Typ [1]	Max	
Cı	input capacitance	S0, S1, S2, and \overline{E} pins; V _I = 0 V, 1.8 V, or V _{CC} ; f = 1 MHz	-	1.5	3	pF

- [1] Typical values are measured at T_{amb} = 25 °C.
- [2] ΔV_0 here is the maximum variation of output voltage of an enabled analog channel when current is injected into any disabled channel.
- [3] I_{SW} = total current injected into all disabled channels.







12. Dynamic characteristics

Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground 0 V); for test circuit see Fig. 10.

Symbol	Parameter	Conditions		25 °C			°C to 5 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
t _{pd}	propagation delay	Z to Yn, Yn to Z; $C_L = 50 \text{ pF}$; [1] see Fig. 7								
		V _{CC} = 1.8 V ± 10%	-	10	23	-	25	-	26	ns
		V _{CC} = 2.5 V ± 10%	-	6	10	-	11	-	12	ns
		V _{CC} = 3.3 V ± 10%	-	3	6	-	7	-	8	ns
		V _{CC} = 5 V ± 10%	-	2	4	-	5	-	5	ns
		V _{CC} = 5 V ± 10%; C _L = 15 pF	-	1	3	-	3	-	3	ns
t _{pd}	transition time between inputs	Sn to Z; $R_L = 10 \text{ k}\Omega$; $C_L = 50 \text{ pF}$; [1] see <u>Fig. 8</u>								
		V _{CC} = 1.8 V ± 10%	-	54	93	-	95	-	95	ns
		V _{CC} = 2.5 V ± 10%	-	41	67	-	74	-	74	ns
		V _{CC} = 3.3 V ± 10%	-	36	61	-	71	-	71	ns
		V _{CC} = 5.0 V ± 10%	-	33	60	-	72	-	72	ns
		V _{CC} = 5.0 V ± 10%; C _L = 15 pF	-	31	58	-	70	-	70	ns
		Sn to Yn; $R_L = 10 \text{ k}\Omega$; $C_L = 50 \text{ pF}$; [1] see Fig. 8								
		V _{CC} = 1.8 V ± 10%	-	111	361	-	366	-	366	ns
		V _{CC} = 2.5 V ± 10%	-	99	352	-	352	-	353	ns
		V _{CC} = 3.3 V ± 10%	-	96	346	-	346	-	346	ns
		V _{CC} = 5.0 V ± 10%	-	96	338	-	339	-	340	ns
		V _{CC} = 5.0 V ± 10%; C _L = 15 pF	-	39	93	-	95	-	96	ns
t _{en}	enable time	\overline{E} to Z, \overline{E} to Yn; $R_L = 10 \text{ k}\Omega$; [2] $C_L = 50 \text{ pF}$; see $\overline{Fig. 9}$								
		V _{CC} = 1.8V ± 10%	-	15	25	-	27	-	29	ns
		V _{CC} = 2.5 V ± 10%	-	12	17	-	18	-	18	ns
		V _{CC} = 3.3 V ± 10%	-	12	17	-	18	-	18	ns
		V _{CC} = 5 V ± 10%	-	12	17	-	18	-	18	ns
		V _{CC} = 5 V ± 10%; C _L = 15 pF	-	11	16	-	17	-	17	ns

Symbol	Parameter	Conditions	25 °C		-40 °C to +85 °C			-40 °C to +125 °C		
			Min	Min Typ		Min	Max	Min	Max	
t _{dis}	disable time	\overline{E} to Z, \overline{E} to Yn; R _L = 10 k Ω ; [3] C _L = 50 pF; S1 = GND; see Fig. 9								
		V _{CC} = 1.8 V ± 10%	-	22	48	-	49	-	50	ns
		V _{CC} = 2.5 V ± 10%	-	20	41	-	42	-	42	ns
		V _{CC} = 3.3 V ± 10%	-	18	38	-	38	-	38	ns
		V _{CC} = 5 V ± 10%	-	18	33	-	34	-	34	ns
		V _{CC} = 5 V ± 10%; C _L = 15 pF	-	3	5	-	5	-	6	ns
		\overline{E} to Z, \overline{E} to Yn; R _L = 10 k Ω ; [3] C _L = 50 pF; S1 = V _{CC} ; see Fig. 9								
		V _{CC} = 1.8 V ± 10%	-	14	74	-	74	-	74	ns
		V _{CC} = 2.5 V ± 10%	-	11	73	-	73	-	73	ns
		V _{CC} = 3.3 V ± 10%	-	10	72	-	73	-	73	ns
		V _{CC} = 5 V ± 10%	-	9	72	-	72	-	72	ns
		V _{CC} = 5 V ± 10%; C _L = 15 pF	-	6	36	-	37	-	38	ns
t _{b-m}	break-before- make time	$R_L = 10 \text{ k}\Omega; C_L = 15 \text{ pF}; \text{ Yn to Z}$								
		V _{CC} = 1.8 V ± 10%	1	35	-	1	-	1	-	ns
		V _{CC} = 2.5 V ± 10%	1	30	-	1	-	1	-	ns
		V _{CC} = 3.3 V ± 10%	1	30	-	1	-	1	-	ns
		V _{CC} = 5 V ± 10%	1	30	-	1	-	1	-	ns

^[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

Table 10. Dynamic characteristics

Symbol	Parameter	Conditions	T _{amb}	T _{amb} = -40 °C to +125 °C			
			Min	Тур	Max		
Q _{inj}	charge injection	$V_{I} = 0.5V_{CC}$; $R_{S} = 0 \Omega$; $C_{L} = 100 pF$					
		V _{CC} = 1.8 V ± 10%	-	1	-	рC	
		V _{CC} = 2.5 V ± 10%	-	2	-	рC	
		V _{CC} = 3.3 V ± 10%	-	3	-	рC	
		V _{CC} = 5 V ± 10%	-	8	-	рC	
α_{iso}	isolation (OFF-state)	$V_{bias} = 0.5V_{CC}$; $V_{I} = 200 \text{ mVpp}$; $R_{L} = 50 \Omega$; $C_{L} = 5 \text{ pF}$; $f = 100 \text{ kHz}$					
		V _{CC} = 1.8 V ± 10%	-	-125	-	dB	
		V _{CC} = 2.5 V ± 10%	-	-125	-	dB	
		V _{CC} = 3.3 V ± 10%	-	-125	-	dB	
		V _{CC} = 5 V ± 10%	-	-125	-	dB	
		$V_{bias} = 0.5V_{CC}; V_{I} = 200 \text{ mVpp};$ $R_{L} = 50 \Omega; C_{L} = 5 \text{ pF}; f = 1 \text{ MHz}$					
		V _{CC} = 1.8 V ± 10%	-	-100	-	dB	
		V _{CC} = 2.5 V ± 10%	-	-100	-	dB	
		V _{CC} = 3.3 V ± 10%	-	-100	-	dB	
		V _{CC} = 5 V ± 10%	-	-100	-	dB	

^[2] t_{en} is the same as t_{PZH} and t_{PZL} .

^[3] t_{dis} is the same as t_{PLZ} and t_{PHZ} .

Symbol	Parameter	Conditions	T _{amb} :	= -40 °C to +	125 °C	Unit
			Min	Тур	Max	
X _{talk}	crosstalk	$V_{bias} = 0.5V_{CC}; V_{I} = 200 \text{ mVpp};$ $R_{L} = 50 \Omega; C_{L} = 5 \text{ pF}; f = 100 \text{ kHz}$				
		V _{CC} = 1.8 V ± 10%	-	-105	-	dB
		V _{CC} = 2.5 V ± 10%	-	-105	-	dB
		V _{CC} = 3.3 V ± 10%	-	-105	-	dB
		V _{CC} = 5 V ± 10%	-	-105	-	dB
		$V_{bias} = 0.5V_{CC}; V_{I} = 200 \text{ mVpp};$ $R_{L} = 50 \Omega; C_{L} = 5 \text{ pF}; f = 1 \text{ MHz}$				
		V _{CC} = 1.8 V ± 10%	-	-80	-	dB
		V _{CC} = 2.5 V ± 10%	-	-80	-	dB
		V _{CC} = 3.3 V ± 10%	-	-80	-	dB
		V _{CC} = 5 V ± 10%	-	-80	-	dB
BW	Bandwidth	$V_{bias} = 0.5V_{CC}$; $V_{I} = 200 \text{ mVpp}$; $R_{L} = 50 \Omega$; $C_{L} = 5 \text{ pF}$				
		V _{CC} = 1.8 V ± 10%	-	270	-	MHz
		V _{CC} = 2.5 V ± 10%	-	300	-	MHz
		V _{CC} = 3.3 V ± 10%	-	315	-	MHz
		V _{CC} = 5 V ± 10%	-	325	-	MHz

12.1. Waveforms and test circuit

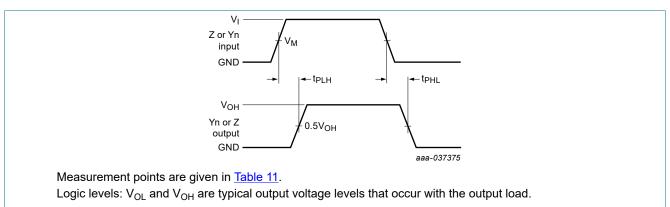
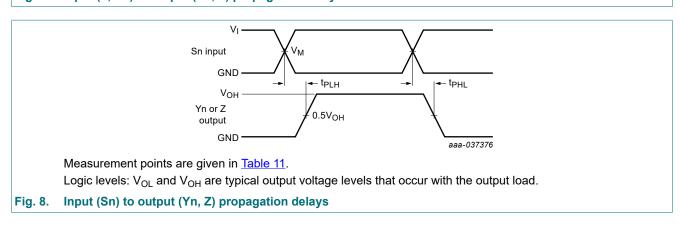


Fig. 7. Input (Z, Yn) to output (Yn, Z) propagation delays



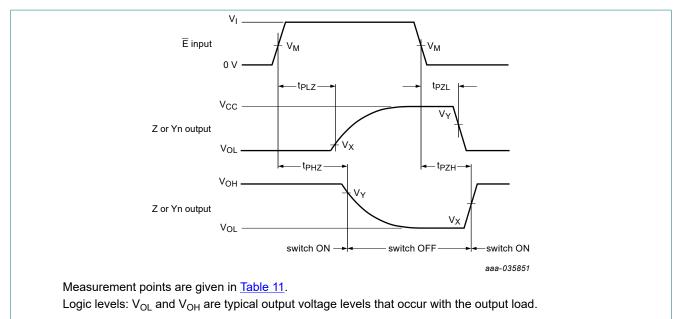
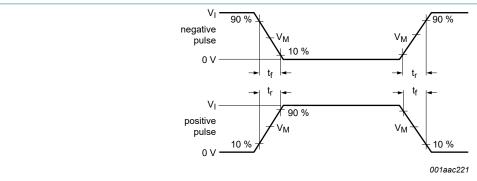


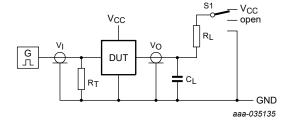
Fig. 9. Enable and disable times

Table 11. Measurement points

Input		Output			
V _M	VI	V _X	V _Y		
0.5 × V _{CC}	V _{CC}	$V_{OL} + 0.1(V_{CC} - V_{OL})$	0.9 × V _{OH}		



a. Input pulse definition



b. Test circuit

Test data is given in Table 12.

Definitions for test circuit:

R_L = load resistance;

C_L = load capacitance including jig and probe capacitance;

 R_{T} = termination resistance should be equal to the output impedance Z_{O} of the pulse generator.

Fig. 10. Test circuit for measuring switching times

Table 12. Test data

Test	Input	Output				S1 position	
	Control \overline{E} , Sn Switch Yn (Z) t_r , t_f Switch Z (Yn)						
	VI	VI		C _L	R _L		
t _{PHL,} t _{PLH}	V _{CC}	V _{CC}	< 5 ns	50 pF	-	open	
t _{PHZ} , t _{PZH}	V _{CC}	V _{CC}	< 5 ns	50 pF	10 kΩ	GND	
t _{PLZ} , t _{PZL}	V _{CC}	V _{CC}	< 5 ns	50 pF	10 kΩ	V _{CC}	

13. Application information

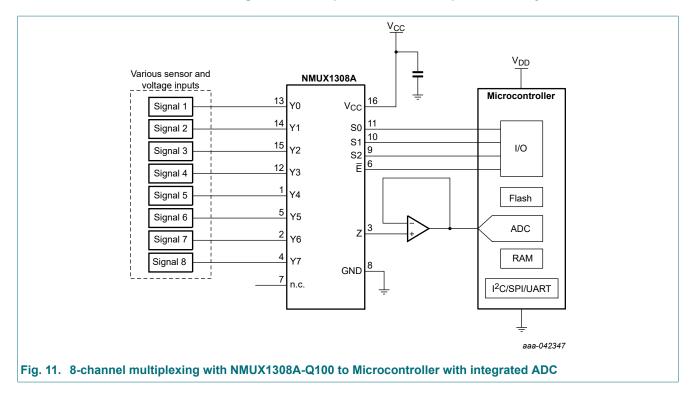
NMUX1308A-Q100

The NMUX1308A-Q100 is a versatile CMOS bi-directional 8-channel (8:1) analog switch designed for general-purpose use, operating within a voltage range of 1.5 V to 5.5 V. It features 5.5V overvoltage tolerant digital inputs and is compatible with 1.8 V CMOS levels, eliminating the need for voltage translation. The device has also been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1).

Each analog signal pin on the NMUX1308A-Q100 incorporates injection current control circuitry. This innovative feature serves to isolate overvoltage spikes on disconnected analog signal pins, preventing them from affecting the connected analog signal path. Another protective feature includes Fail-Safe-Logic. These attributes make the NMUX130X family of devices the ideal choice for applications aiming to simplify signal management and reduce system complexity, resulting in a lower component count and a smaller PCB area. This utilization allows users to adopt a design approach centered around modularity, reuse, and scalability.

Typical application schematic

A typical example is provided in Fig. 11. In this instance, various sensor and voltage inputs are sequentially accessed by the input of the SAR ('Successive Approximation Register') ADC. In the example below, the SAR ADC is integrated in the Microcontroller. The operational amplifier serves the purpose of satisfying the SAR ADC recommendation of being driven with a low-impedance source, especially when input sensors or signals have large output impedance. This enhancement improves the performance of the SAR ADC, ensuring fast and accurate conversions while minimizing errors during the sampling process. Additionally, the op-amp eliminates potential error sources, such as ADC input leakage current, that can cause a small drop, resulting in a minor voltage error across the analog multiplexer.

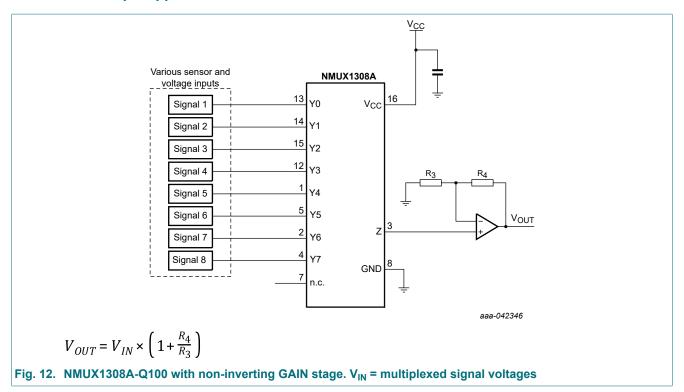


The benefits of this design type include the capability to route and switch multiple analog signals through a single channel. This is particularly crucial when the number of ADC input channels is limited.

Table 13. Example design parameters with NMUX1308A-Q100

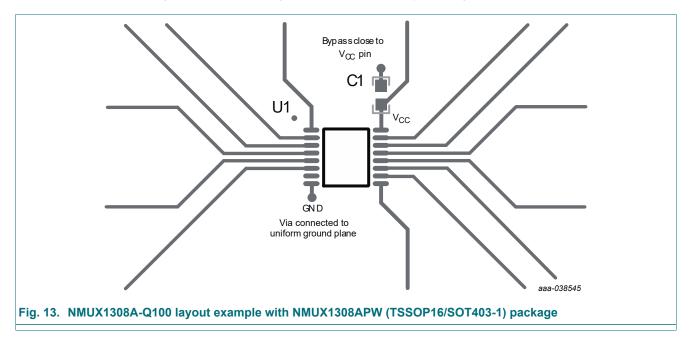
Important Design Parameters	Example Value
Supply range (V _{CC})	1.5 V to 5.5 V
Analog input voltage range	0 V to V _{CC} (rail-to-rail)
Control input logic	1.8 V compatible (5.5 V overvoltage tolerant)
I _{SW} independent switch current (maximum)	50 mA
Total analog input continuous current to GND (maximum)	100 mA

Additional example application



NMUX1308A-Q100 layout example

The image provided below ($\underline{\text{Fig. 13}}$) offers a glimpse into an example PCB layout with the (PW) package. Bypass capacitors should be positioned near the V_{CC} pin, and the GND pin should be connected to external/internal GND planes. A uniform GND plane helps in reducing noise and minimizing loop inductance, thereby ensuring optimal performance.



Layout recommendations

As with all board designs, proper layout techniques should be employed. Some quick good layout practices and considerations are listed below for quick reference.

- Ceramic capacitors with low ESR should be used to properly decouple or bypass power-supply pins. Ceramic capacitors
 with high temperature coefficients and low dissipation factors include X5R, X7R and NP0. The recommended minimum
 value is 0.1 µF.
- For improved noise suppression, additional bypass capacitors can be implemented. It is a common practice to use two
 different capacitor values to ensure proper filtering of both low-frequency and high-frequency transients. The smaller
 capacitor, typically in a 0402 package, is placed very near the device pin, while the larger capacitor is positioned farther
 away.
- To minimize coupling and improve performance all switching nets should travel across a uniform ground plane. Reducing crosstalk can also be achieved by separating traces with a small polygon ground plane.
- Net traces should only have serpentine or 45° bend. Sharper bends, such as 90° should be avoided.

14. Package outline

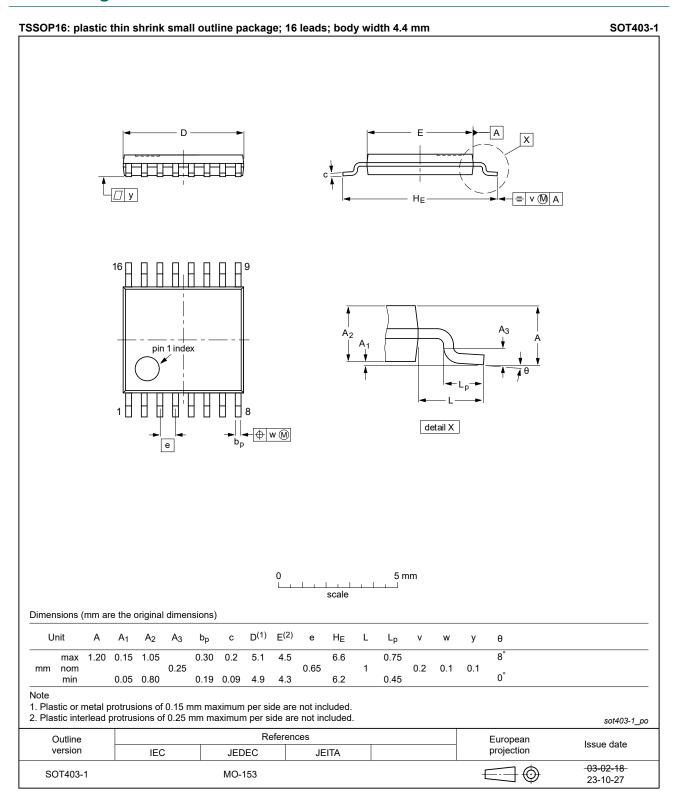


Fig. 14. Package outline SOT403-1 (TSSOP16)

DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

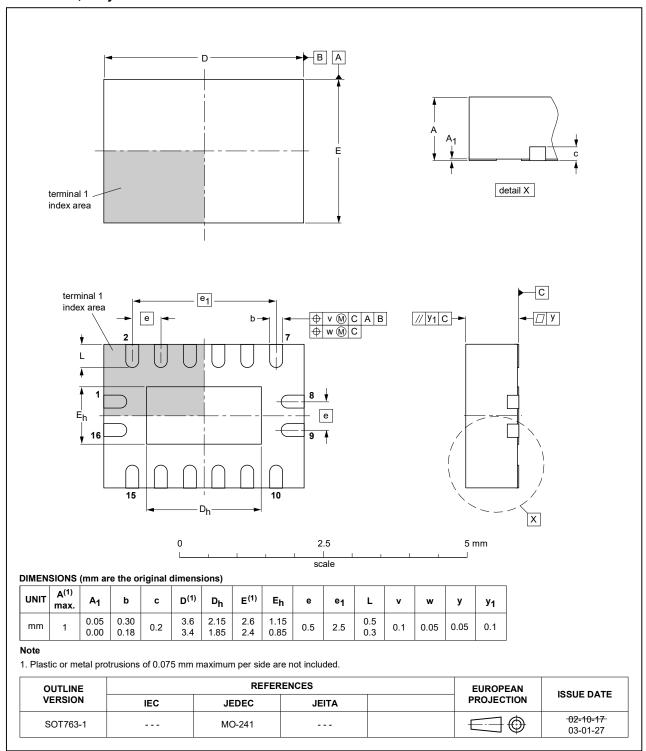


Fig. 15. Package outline SOT763-1 (DHVQFN16)

15. Abbreviations

Table 14. Abbreviations

Acronym	Description				
ANSI	American National Standards Institute				
CDM	Charged Device Model				
CMOS	Complementary Metal-Oxide Semiconductor				
DUT	Device Under Test				
ESDA	ElectroStatic Discharge Association				
ESD	ElectroStatic Discharge				
НВМ	Human Body Model				
JEDEC	Joint Electron Device Engineering Council				

16. Revision history

Table 15. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
NMUX1308A_Q100 v. 1	20250516	Product data sheet	-	-

17. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Nexperia and its customer, unless Nexperia and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Nexperia product is deemed to offer functions and qualities beyond those described in the Product data sheet.

Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Nexperia takes no responsibility for the content in this document if provided by an information source outside of Nexperia.

In no event shall Nexperia be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Nexperia's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the Terms and conditions of commercial sale of Nexperia.

Right to make changes — Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use in automotive applications — This Nexperia product has been qualified for use in automotive applications. Unless otherwise agreed in writing, the product is not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or

equipment, nor in applications where failure or malfunction of an Nexperia product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Nexperia and its suppliers accept no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Nexperia products, and Nexperia accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Nexperia product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Nexperia does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Nexperia products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Nexperia does not accept any liability in this respect

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — Nexperia products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nexperia.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Nexperia hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Nexperia products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

Contents

1. General description	1
2. Features and benefits	1
3. Applications	1
4. Ordering information	2
5. Marking	
6. Functional diagram	2
7. Pinning information	
7.1. Pinning	
7.2. Pin description	
8. Functional description	
8.1. Overview	
8.2. Key features	
9. Limiting values	
10. Recommended operating conditions	7
11. Static characteristics	
12. Dynamic characteristics	
12.1. Waveforms and test circuit	
13. Application information	
14. Package outline	
15. Abbreviations	
16. Revision history	
17. Legal information	
-5	·

For more information, please visit: http://www.nexperia.com For sales office addresses, please send an email to: salesaddresses@nexperia.com Date of release: 16 May 2025

[©] Nexperia B.V. 2025. All rights reserved